Erratum to: Developments in Time-Division Multiplexing of X-ray Transition-Edge Sensors

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In the original paper, we described two different architectures of a time-division-SQUID multiplexer: a “mature” architecture (Section 2) and a “new” architecture (Section 3). For the new architecture, the stated value of the Joule-power dissipation of the multiplexer chip was incorrect.

The corrected last sentence of the first paragraph of Section 3 is as follows:

There is no SQ2 on the multiplexer chip. Per-column power dissipation in the multiplexer chip(s) is 1.8 nW. This value was determined via measurement of current and voltage during standard operation of the chips.

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